

**MMBT2907A** 

PNP SMALL SIGNAL SURFACE MOUNT TRANSISTOR

#### **Features**

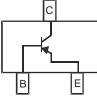
- **Epitaxial Planar Die Construction**
- Complementary NPN Type Available (MMBT2222A)
- Ideal for Low Power Amplification and Switching
- Lead, Halogen and Antimony Free, RoHS Compliant (Note 2)
- "Green" Device (Note 3)
- Qualified to AEC-Q 101 Standards for High Reliability

## **Mechanical Data**

- Case: SOT-23
- Case Material: Molded Plastic, "Green" Molding Compound, • Note 3. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D •
- Terminal Connections: See Diagram
- Terminals: Matte Tin Finish annealed over Alloy 42 leadframe • (Lead Free Plating) Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.008 grams (approximate)



Top View



**Device Schematic** 

#### Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-60	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-60	V
Emitter-Base Voltage	V <sub>EBO</sub>	-5.0	V
Collector Current - Continuous (Note 1)	lc	-600	mA
Peak Collector Current	I <sub>CM</sub>	-800	mA

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 1)	PD	300	mW
Thermal Resistance, Junction to Ambient (Note 1)	R <sub>0JA</sub>	417	°C/W
Operating and Storage and Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf. Notes:

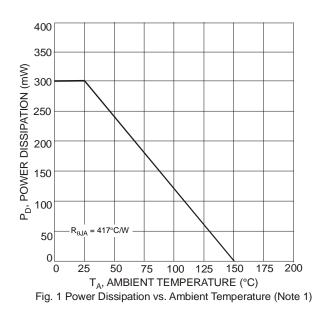
No purposefully added lead. Halogen and Antimony Free
Product manufactured with Data Code V9 (week 33, 2008) and newer are built with Green Molding Compound. Product manufactured prior to Date Code V9 are built with Non-Green Molding Compound and may contain Halogens or Sb<sub>2</sub>O<sub>3</sub> Fire Retardants.

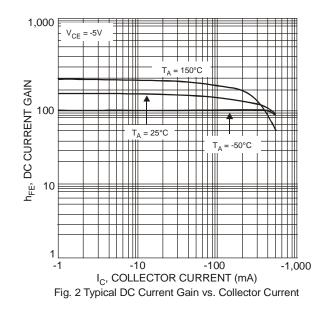


# Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 4)				_	
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	-60		V	$I_{C} = -10\mu A, I_{E} = 0$
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	-60		V	$I_{\rm C} = -10 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	-5.0	—	V	$I_{E} = -10\mu A, I_{C} = 0$
Collector Cutoff Current	I <sub>CBO</sub>	_	-10	nA μA	V <sub>CB</sub> = -50V, I <sub>E</sub> = 0 V <sub>CB</sub> = -50V, I <sub>E</sub> = 0, T <sub>A</sub> = 125°C
Collector Cutoff Current	I <sub>CEX</sub>		-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -0.5V$
Base Cutoff Current	I <sub>BL</sub>		-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -0.5V$
ON CHARACTERISTICS (Note 4)					· · ·
DC Current Gain	h <sub>FE</sub>	75 100 100 100 50	  300 	_	$\begin{split} I_{C} &= -100 \mu A, \ V_{CE} &= -10V \\ I_{C} &= -1.0 m A, \ V_{CE} &= -10V \\ I_{C} &= -10 m A, \ V_{CE} &= -10V \\ I_{C} &= -150 m A, \ V_{CE} &= -10V \\ I_{C} &= -500 m A, \ V_{CE} &= -10V \end{split}$
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	_	-0.4 -1.6	V	I <sub>C</sub> = -150mA, I <sub>B</sub> = -15mA I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	_	-1.3 -2.6	V	$I_{C} = 150$ mA, $I_{B} = 15$ mA $I_{C} = 500$ mA, $I_{B} = 50$ mA
SMALL SIGNAL CHARACTERISTICS					•
Output Capacitance	C <sub>obo</sub>	_	8.0	pF	$V_{CB} = -10V$ , f = 1.0MHz, I <sub>E</sub> = 0
Input Capacitance	Cibo	_	30	pF	$V_{EB} = -2.0V$ , f = 1.0MHz, I <sub>C</sub> = 0
Current Gain-Bandwidth Product	f <sub>T</sub>	200	—	MHz	$V_{CE} = -20V$ , $I_C = -50mA$ , f = 100MHz
SWITCHING CHARACTERISTICS					
Turn-On Time	t <sub>off</sub>	_	45	ns	<u> </u>
Delay Time	t <sub>d</sub>	—	10	ns	$V_{\rm CC} = -30V, I_{\rm C} = -150mA,$
Rise Time	tr	—	40	ns	$I_{B1} = -15 \text{mA}$
Turn-Off Time	t <sub>off</sub>		100	ns	
Storage Time	ts		80	ns	V <sub>CC</sub> = -6.0V, I <sub>C</sub> = -150mA, I <sub>B1</sub> = I <sub>B2</sub> = -15mA
Fall Time	t <sub>f</sub>	_	30	ns	$_{181}{182} = -10114$

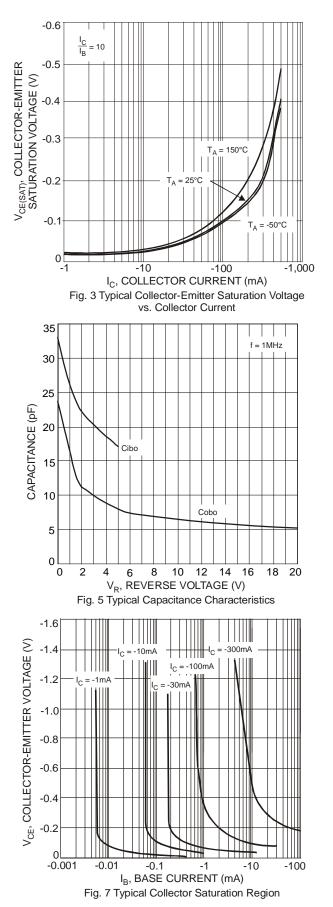
Notes: 4. Short duration pulse test used to minimize self-heating effect.

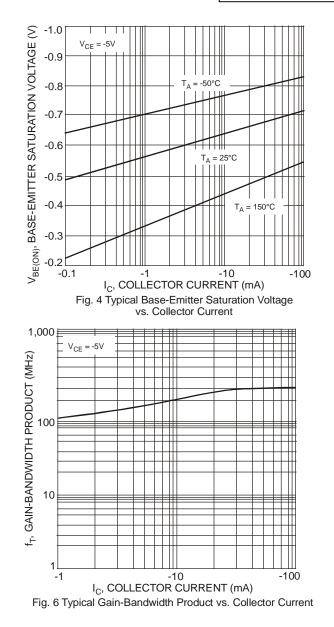














#### Ordering Information (Note 5)

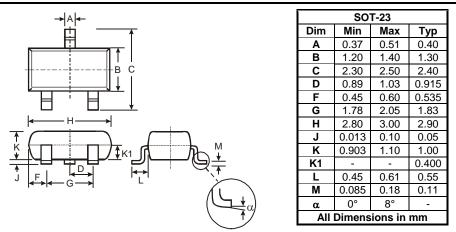
Part Number	Case	Packaging
MMBT2907A-7-F	SOT-23	3000/Tape & Reel

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

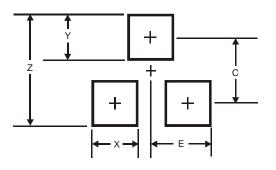
#### **Marking Information**

Date Code Key						$\Box$				Month	(0/11 0		,					
Year 199	998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014	2015
Code J	J	К	L	М	Ν	Р	R	S	Т	U	V	W	Х	Y	Z	Α	В	С
Month J Code	Jan 1	F	Feb	Mar 3	·	Apr 4	<b>Ma</b> 5	у	Jun 6	Jul 7		Aug 8	Sep 9		Oct	Nov N	<u>,    </u>	Dec

## **Package Outline Dimensions**



## **Suggested Pad Layout**



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35

#### IMPORTANT NOTICE

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. Diodes Incorporated does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

LIFE SUPPORT

Diodes Incorporated products are not authorized for use as critical components in life support devices or systems without the expressed written approval of the President of Diodes Incorporated.